## SURFACE MOUNT SCHOTTKY BARRIER RECTIFIERS

Reverse Voltage - 20 to 40 V

Forward Current - 1 A

### **Features**

- Plastic package has Underwriters Laboratory Classification 94V-0
- Metal silicon junction, majority carrier conduction
- For surface mount applications
- Guard ring for overvoltage protection
- Low power loss, high efficiency
- High current capability, Low forward voltage drop
- High surge capability

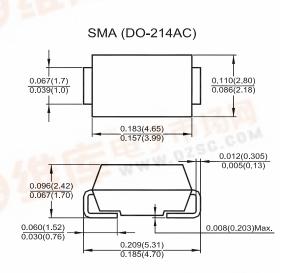
### **Mechanical Data**

• Case: SMA (DO-214AC) molded plastic case

• Terminals: Solder plate, solderable per MIL-STD -750, method 2026

• Polarity: Color band denotes cathode end

• Mounting Position: Any



Dimensions in inches and (millimeters)

### **Maximum Ratings and Electrical Characteristics**

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, resistive or inductive load, for eanacitive load derate by 20%

Parameter		Symbols	SS5817	SS5818	SS5819	Units
Maximum Repetitive Peak Reverse Voltage		$V_{RRM}$	20	30	40	V
Maximum RMS Voltage		$V_{RMS}$	14	21	28	V
Maximum DC Blocking Voltage		V <sub>DC</sub>	20	30	40	V
Maximum Average Forward Rectified Current 0.375" (9.5 mm) Load Length at $T_L = 90$ °C		I <sub>(AV)</sub>	1			А
Peak Forward Surge Current 8.3mS Single Half Sine-wave Superimposed on Rated Load (JEDEC Method) at T <sub>L</sub> = 70 °C		I <sub>FSM</sub>	25		А	
Maximum Instantaneous Forward Voltage at 1 A		V <sub>F</sub>	0.45	0.55	0.6	V
Maximum Instantaneous Reverse Current at Rated	at T <sub>A</sub> = 25°C	- I <sub>R</sub>	0.5			mA
DC Blocking Voltage	at T <sub>A</sub> =100 °C		10			mA
Typical Junction Capacitance 1)		CJ	110			pF
Typical Thermal Resistance 2)		$R_{\theta JA}$	88			°C/W
Operating and Storage Temperature Range		T <sub>J</sub> ,T <sub>S</sub>	- 65 to + 125			°С

<sup>1)</sup> Measured at 1 MHz and reverse voltage of 4 volts.

<sup>&</sup>lt;sup>2)</sup> Thermal Resistance (from Junction to Ambient) Vertical P.C.B Mounted, with 1.5 X 1.5" (38 X 38 mm) copper pads. WWW.DZSC







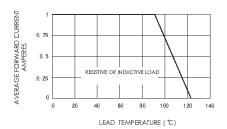




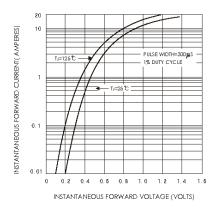


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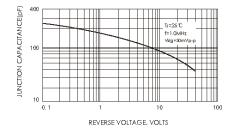
#### FIG.1-FORWARD CURRENT DERATING CURVE



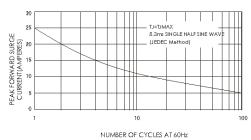
#### FIG.3-TYPICAL INSTANTANEOUS FORWARD **CHARACTERISTICS**



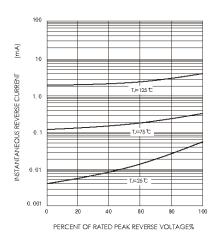
### FIG.5-TYPICAL JUNCTION CAPACITANCE



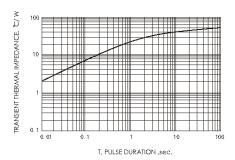
#### FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT



#### FIG.4-TYPICAL REVERSE CHARACTERISTICS



### FIG.6-TYPICAL TRANSIENT THERMAL IMPEDANCE





# SEMTECH ELECTRONICS LTD.

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